

	Type	Hits	Search Text
1	BRS	104	(HEMT or MODFET or TEGFET or HFET) and (InAlAs with AlGaAs)
2	BRS	18	(schottky near barrier) same (insulat\$5 near layer) same (doped near layer)
3	BRS	8	((enhanc\$5 or increas\$5) with (schottky with barrier)) same (insulat\$5 with layer) same (doped with layer)
4	BRS	296	modulation with AlGaAs
5	BRS	151	(modulation near2 doped) with AlGaAs
6	BRS	100	S5 and (HFET or MODFET or HEMT)
7	BRS	489	BASICHAS.XA.
8	IS&R	2	(("6313046") or ("6333556")).PN.
9	IS&R	1	("5847443").PN.
10	BRS	30	("5847443").URPN.
11	IS&R	2	("5504042").PN.
12	BRS	46	("5504042").URPN.

	DBs
1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
8	USPAT
9	USPAT
10	USPAT
11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
12	USPAT